



Bidirectional TVS Diodes SMCJ5.0CA 9.2VC Transient Voltage Suppression UL Recognized

Our Product Introduction

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Basic Information

- Place of Origin: Shenzhen, Guangdong, China
- Brand Name: SOCAY
- Certification: UL, REACH, RoHS, ISO
- Model Number: SMCJ5.0CA
- Minimum Order Quantity: 3000PCS
- Price: Negotiable
- Delivery Time: 5-8 work days



Product Specification

- SMCJ5.0CA Name: TVS Diodes
- SMCJ5.0CA Package Type: DO-214AB/SMC
- SMCJ5.0CA V_{rw}: 5.0V
- SMCJ5.0CA V_{br}@I_t (Min.): 6.40V
- SMCJ5.0CA V_{br}@I_t (Max.): 7.00V
- SMCJ5.0CA I_t: 10mA
- SMCJ5.0CA V_c@I_{pp}: 9.2V
- SMCJ5.0CA I_{pp}: 163.04A
- SMCJ5.0CA I_r@V_{rw}: 1000μA
- Storage Temperature Range: -55 To +150
- Highlight: **Bidirectional TVS Diodes,
TVS Diodes SMCJ5.0CA,
TVS Transient Voltage Suppression**



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Product Description

Bi-directional TVS Diode SMCJ5.0CA, 9.2VC Rransient Voltage Suppressor, UL Recognized

DATASHEET: [SMCJ_v2107.1 .pdf](#)

TVS Diode SMCJ5.0CA Description:

The TVS Diode SMCJ5.0CA is designed specifically to protect sensitive electronic equipment from voltage transients induced by lightning and other transient voltage events.

TVS Diode SMCJ5.0CA Maximum Ratings ($T_A=25$ unless otherwise noted):

TVS Diode Parameter	Symbol	Value	TVS Diode Unit
SMCJ5.0CA Peak Pulse Power Dissipation with a 10/1000 μ s waveform (Fig.1)(Note 1), (Note 2)	P_{PPM}	1500	Watts
SMCJ5.0CA Peak Pulse Current with a 10/1000 μ s waveform.(Note1, Fig.3)	I_{PP}	See Next Table	Amps
Power Dissipation on Infinite Heat Sink at $T_L=75^\circ\text{C}$	$P_{M(AV)}$	6.5	Watt
SMCJ5.0CA Peak Forward Surge Current, 8.3ms Single Half Sine Wave (Note 3)	I_{FSM}	200	Amps
Maximum Instantaneous Forward Voltage at 25A for Unidirectional Only (Note 4)	V_F	3.5/5.0	Voltage
SMCJ5.0CA Operating junction and Storage Temperature Range.	T_J, T_{STG}	-55 to +150	
Notes: 1. Non-repetitive current pulse, per Fig. 3 and derated above $T_A = 25$ per Fig. 2. 2. Mounted on 5.0mm x 5.0mm (0.03mm thick) Copper Pads to each terminal. 3. 8.3ms single half sine-wave, or equivalent square wave, Duty cycle = 4 pulses per minutes maximum. 4. $V_F < 3.5\text{V}$ for $V_{BR} < 200\text{V}$ and $V_F < 6.5\text{V}$ for $V_{BR} > 201\text{V}$.			

TVS Diode SMCJ5.0CA Electrical Characteristics ($T_A=25$ unless otherwise noted):

TVS Diode Part Number		Marking		TVS Diode Reverse Stand-Off Voltage VRWM (V)	TVS Diode Breakdown Voltage VBR (V) @IT		Test Current IT (mA)	TVS Diode Maximum Clamping Voltage VC @IPP (V)	TVS Diode Maximum Peak Pulse Current IPP (A)	Maximum Reverse Leakage IR @VRWM (μA)
Uni	Bi	Uni	Bi		MIN	MAX				
SMCJ5.0A	SMCJ5.0CA	GD E	BD E	5.0	6.40	7.00	10	9.2	163.04	1000
SMCJ6.0A	SMCJ6.0CA	GD G	BD G	6.0	6.67	7.37	10	10.3	145.63	1000
SMCJ6.5A	SMCJ6.5CA	GD K	BD K	6.5	7.22	7.98	10	11.2	133.93	500
SMCJ7.0A	SMCJ7.0CA	GD M	BD M	7.0	7.78	8.60	10	12.0	125.00	200
SMCJ7.5A	SMCJ7.5CA	GD P	BD P	7.5	8.33	9.21	1	12.9	116.28	100
SMCJ8.0A	SMCJ8.0CA	GD R	BD R	8.0	8.89	9.83	1	13.6	110.29	50
SMCJ8.5A	SMCJ8.5CA	GD T	BD T	8.5	9.44	10.40	1	14.4	104.17	20
SMCJ9.0A	SMCJ9.0CA	GD V	BD V	9.0	10.00	11.10	1	15.4	97.40	10
SMCJ10A	SMCJ10CA	GD X	BD X	10.0	11.10	12.30	1	17.0	88.24	5

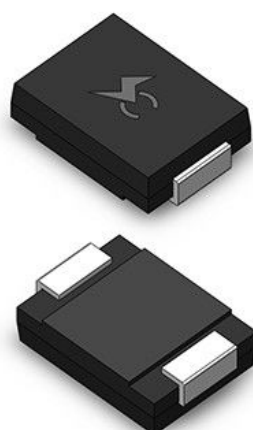
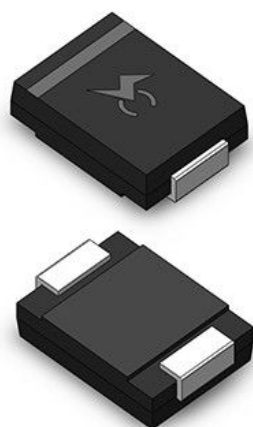
Electrical Characteristics (T_A=25°C unless otherwise noted)

Part Number		Marking		Reverse Stand-Off Voltage V _{RRM} (V)	Breakdown Voltage V _{BR} (V) @I _r		Test Current I _r (mA)	Maximum Clamping Voltage V _C @I _{CC} (V)	Maximum Peak Pulse Current I _{PP} (A)	Maximum Reverse Leakage I _s @V _{RRM} (μA)
Uni	Bi	Uni	Bi		MIN	MAX				
SMCJ5.0A	SMCJ5.0CA	GDE	BDE	5.0	6.40	7.00	10	9.2	163.04	1000
SMCJ6.0A	SMCJ6.0CA	GDG	BDG	6.0	6.67	7.37	10	10.3	145.63	1000
SMCJ6.5A	SMCJ6.5CA	GDK	BDK	6.5	7.22	7.98	10	11.2	133.93	500
SMCJ7.0A	SMCJ7.0CA	GDM	BDM	7.0	7.78	8.60	10	12.0	125.00	200
SMCJ7.5A	SMCJ7.5CA	GDP	BDP	7.5	8.33	9.21	1	12.9	116.28	100
SMCJ8.0A	SMCJ8.0CA	GDR	BDR	8.0	8.89	9.83	1	13.6	110.29	50
SMCJ8.5A	SMCJ8.5CA	GDT	BDT	8.5	9.44	10.40	1	14.4	104.17	20
SMCJ9.0A	SMCJ9.0CA	GDV	BDV	9.0	10.00	11.10	1	15.4	97.40	10
SMCJ10A	SMCJ10CA	GDX	BDX	10.0	11.10	12.30	1	17.0	88.24	5
SMCJ11A	SMCJ11CA	GDZ	BDZ	11.0	12.20	13.50	1	18.2	82.42	5
SMCJ12A	SMCJ12CA	GEE	BEE	12.0	13.30	14.70	1	19.9	75.38	5
SMCJ13A	SMCJ13CA	GEG	BEG	13.0	14.40	15.90	1	21.5	69.77	5
SMCJ14A	SMCJ14CA	GEK	BEK	14.0	15.60	17.20	1	23.2	64.66	5
SMCJ15A	SMCJ15CA	GEM	BEM	15.0	16.70	18.50	1	24.4	61.48	5
SMCJ16A	SMCJ16CA	GEP	BEP	16.0	17.80	19.70	1	26.0	57.69	5
SMCJ17A	SMCJ17CA	GER	BER	17.0	18.90	20.90	1	27.6	54.35	5
SMCJ18A	SMCJ18CA	GET	BET	18.0	20.00	22.10	1	29.2	51.37	5
SMCJ19A	SMCJ19CA	GEB	BEB	19.0	21.10	23.30	1	30.8	48.73	5
SMCJ20A	SMCJ20CA	GEV	BEV	20.0	22.20	24.50	1	32.4	46.30	5
SMCJ22A	SMCJ22CA	GEX	BEX	22.0	24.40	26.90	1	35.5	42.25	5
SMCJ24A	SMCJ24CA	GEZ	BEZ	24.0	26.70	29.50	1	38.9	38.56	5
SMCJ26A	SMCJ26CA	GFE	BFE	26.0	28.90	31.90	1	42.1	35.63	5
SMCJ28A	SMCJ28CA	GFG	BFG	28.0	31.10	34.40	1	45.4	33.04	5
SMCJ30A	SMCJ30CA	GFK	BFK	30.0	33.30	36.80	1	48.4	30.99	5
SMCJ33A	SMCJ33CA	GFM	BFM	33.0	36.70	40.60	1	53.3	28.14	5
SMCJ36A	SMCJ36CA	GFP	BFP	36.0	40.00	44.20	1	58.1	25.82	5
SMCJ40A	SMCJ40CA	GFR	BFR	40.0	44.40	49.10	1	64.5	23.26	5
SMCJ43A	SMCJ43CA	GFT	BFT	43.0	47.80	52.80	1	69.4	21.61	5

Part Number		Marking		Reverse Stand-Off Voltage V _{RRM} (V)	Breakdown Voltage V _{BR} (V) @I _r		Test Current I _r (mA)	Maximum Clamping Voltage V _C @I _{CC} (V)	Maximum Peak Pulse Current I _{PP} (A)	Maximum Reverse Leakage I _s @V _{RRM} (μA)
Uni	Bi	Uni	Bi		MIN	MAX				
SMCJ45A	SMCJ45CA	GFV	BFV	45.0	50.00	55.30	1	72.7	20.63	5
SMCJ48A	SMCJ48CA	GFX	BFX	48.0	53.30	58.90	1	77.4	19.38	5
SMCJ51A	SMCJ51CA	GFZ	BFZ	51.0	56.70	62.70	1	82.4	18.20	5
SMCJ54A	SMCJ54CA	GGE	BGE	54.0	60.00	66.30	1	87.1	17.22	5
SMCJ58A	SMCJ58CA	GGG	BGG	58.0	64.40	71.20	1	93.6	16.03	5
SMCJ60A	SMCJ60CA	G GK	BGK	60.0	66.70	73.70	1	96.8	15.50	5
SMCJ64A	SMCJ64CA	GGM	BGM	64.0	71.10	78.60	1	103.0	14.56	5
SMCJ70A	SMCJ70CA	G GP	BGP	70.0	77.80	86.00	1	113.0	13.27	5
SMCJ75A	SMCJ75CA	GGR	BGR	75.0	83.30	92.10	1	121.0	12.40	5
SMCJ78A	SMCJ78CA	GGT	BGT	78.0	86.70	95.80	1	126.0	11.90	5
SMCJ80A	SMCJ80CA	GGB	BGB	80.0	88.80	97.60	1	129.6	11.57	5
SMCJ85A	SMCJ85CA	GGV	BGV	85.0	94.40	104.00	1	137.0	10.95	5
SMCJ90A	SMCJ90CA	GGX	BGX	90.0	100.00	111.00	1	146.0	10.27	5
SMCJ100A	SMCJ100CA	GGZ	BGZ	100.0	111.00	123.00	1	162.0	9.26	5
SMCJ110A	SMCJ110CA	GHE	BHE	110.0	122.00	135.00	1	177.0	8.47	5
SMCJ120A	SMCJ120CA	GHG	BHG	120.0	133.00	147.00	1	193.0	7.77	5
SMCJ130A	SMCJ130CA	G HK	BHK	130.0	144.00	159.00	1	209.0	7.18	5
SMCJ140A	SMCJ140CA	G HB	BHB	140.0	155.00	171.00	1	226.8	6.61	5
SMCJ150A	SMCJ150CA	G HM	BHM	150.0	167.00	185.00	1	243.0	6.17	5
SMCJ160A	SMCJ160CA	G HP	BHP	160.0	178.00	197.00	1	259.0	5.79	5
SMCJ170A	SMCJ170CA	G HR	BHR	170.0	189.00	209.00	1	275.0	5.45	5
SMCJ180A	SMCJ180CA	G HT	BHT	180.0	201.00	220.00	1	291.6	5.14	5
SMCJ190A	SMCJ190CA	G HV	BHV	190.0	211.00	232.00	1	307.8	4.87	5
SMCJ200A	SMCJ200CA	G HW	BHW	200.0	224.00	247.00	1	324.0	4.60	5
SMCJ220A	SMCJ220CA	G HX	BHX	220.0	246.00	272.00	1	356.0	4.20	5
SMCJ250A	SMCJ250CA	G HZ	BHZ	250.0	279.00	309.00	1	405.0	3.70	5
SMCJ300A	SMCJ300CA	G JE	BJE	300.0	335.00	371.00	1	486.0	3.10	5
SMCJ350A	SMCJ350CA	G JG	BJG	350.0	391.00	432.00	1	567.0	2.60	5
SMCJ400A	SMCJ400CA	G JK	BJK	400.0	447.00	494.00	1	648.0	2.30	5
SMCJ440A	SMCJ440CA	G JM	BJM	440.0	492.00	543.00	1	713.0	2.10	5

Note:

- Suffix 'A' denotes 5% tolerance device.
- Add suffix 'CA' after part number to specify Bi-Directional devices.
- For Bi-Directional devices having V_{BR} of 10 volts and under, the I_s limit is double.



Description

The SMCJ series is designed specifically to protect sensitive electronic equipment from voltage transients induced by lightning and other transient voltage events.

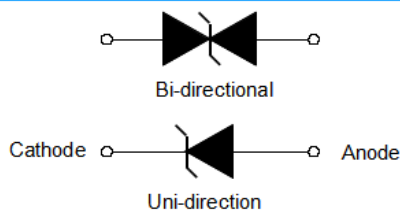
Features

- ◆ For surface mounted applications in order to optimize board space
- ◆ Low leakage
- ◆ Uni and Bidirectional unit
- ◆ Glass passivated junction
- ◆ Low inductance
- ◆ Excellent clamping capability
- ◆ 1500W Peak power capability at $10 \times 1000\mu\text{s}$ waveform Repetition rate (duty cycle):0.01%
- ◆ Fast response time: typically less than 1.0ps from 0 Volts to V_{BR} min
- ◆ Typical I_R less than 5 μA above 12V.
- ◆ High Temperature soldering: 260°C/40 seconds at terminals
- ◆ Typical maximum temperature coefficient $\Delta V_{BR} = 0.1\% \times V_{BR}@25^\circ\text{C} \times \Delta T$
- ◆ Plastic package has Underwriters Laboratory Flammability 94V-0
- ◆ Matte tin lead-free Plated
- ◆ Halogen free and RoHS compliant
- ◆ Typical failure mode is short from over-specified voltage or current
- ◆ Whisker test is conducted based on JEDEC JESD201A per its table 4a and 4c
- ◆ IEC-61000-4-2 ESD 15kV(Air), 8kV (Contact)
- ◆ ESD protection of data lines in accordance with IEC 61000-4-2 (IEC801-2)
- ◆ EFT protection of data lines in accordance with IEC 61000-4-4 (IEC801-4)

Applications

TVS devices are ideal for the protection of I/O interfaces, V_{CC} bus and other vulnerable circuits used in Telecom, Computer, Industrial and Consumer electronic applications.

Functional Diagram



Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak Pulse Power Dissipation with a 10/1000 μs waveform (Fig.1)(Note 1), (Note 2)	P_{PPM}	1500	Watts
Peak Pulse Current with a 10/1000 μs waveform (Note1, Fig.3)	I_{PP}	See Next Table	Amps
Power Dissipation on Infinite Heat Sink at $T_A=75^\circ\text{C}$	P_{MAV}	6.5	Watt
Peak Forward Surge Current, 8.3ms Single Half Sine Wave (Note 3)	I_{FSM}	200	Amps
Maximum Instantaneous Forward Voltage at 25A for Unidirectional Only (Note 4)	V_F	3.5/5.0	Voltage
Operating junction and Storage Temperature Range.	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

Notes:

1. Non-repetitive current pulse, per Fig. 3 and derated above $T_A = 25^\circ\text{C}$ per Fig. 2.
2. Mounted on 5.0mmx 5.0mm (0.03mm thick) Copper Pads to each terminal.
3. 8.3ms single half sine-wave, or equivalent square wave, Duty cycle = 4 pulses per minutes maximum.
4. $V_F < 3.5\text{V}$ for $V_{BR} < 200\text{V}$ and $V_F < 6.5\text{V}$ for $V_{BR} > 201\text{V}$.

Figure 1 - Peak Pulse Power Rating Curve

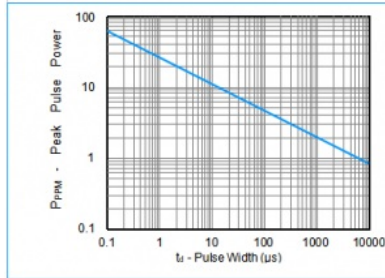


Figure 3 - Pulse Waveform

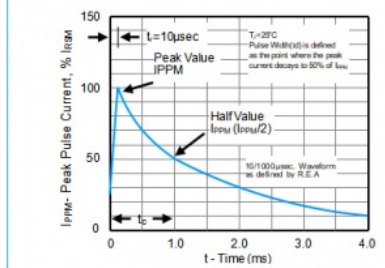


Figure 5 - Steady State Power Derating Curve

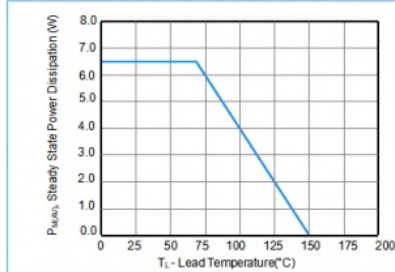


Figure 2 - Pulse Derating Curve

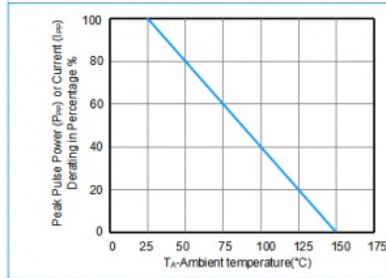


Figure 4 - Typical Junction Capacitance

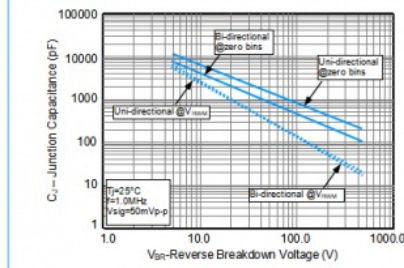
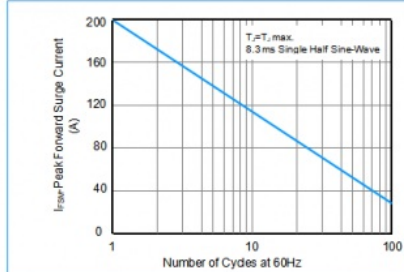
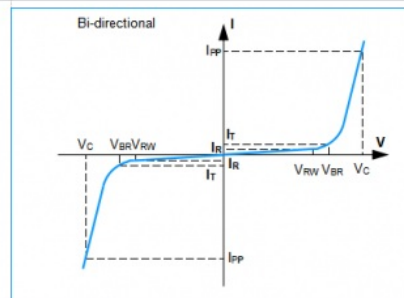
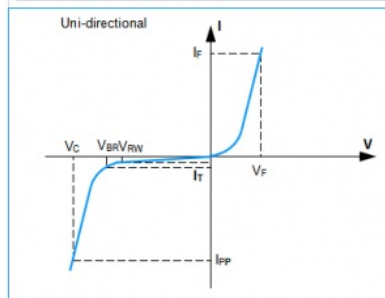


Figure 6 - Maximum Non-Repetitive Surge Current



I-V Curve Characteristics



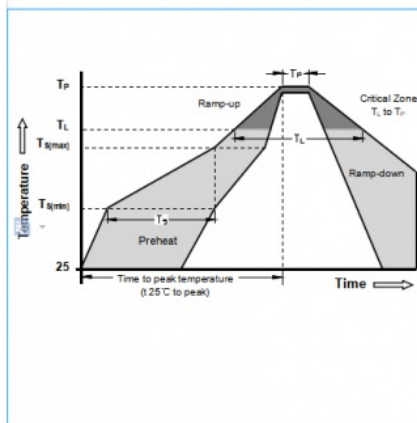
Physical Specifications

Weight	0.007 ounce, 0.21 gram
Case	JEDEC DO-214AB Molded Plastic over glass passivated junction
Polarity	Color band denotes cathode except Bipolar
Terminal	Matte Tin-plated leads, Solderable per JESD22-B102D

Environmental Specifications

Temperature Cycle	JESD22-A104
Pressure Cooker	JESD22-A102
High Temp. Storage	JESD22-A103
HTRB	JESD22-A108
Thermal Shock	JESD22-A106

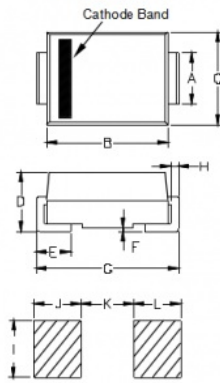
Soldering Parameters



Reflow Condition		Lead-free assembly
Pre Heat	- Temperature Min (T _{S(min)})	150°C
	- Temperature Max (T _{S(max)})	200°C
	- Time (min to max) (T _S)	60 - 180 Seconds
Average ramp up rate (Liquidus Temp T _L) to peak		3°C/second max
T _{S(max)} to T _L - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T _L) (Liquidus)	217°C
	- Time (min to max) (T _L)	60 - 150 Seconds
Peak Temperature (T _P)		260 ±0/-5°C
Time within 5°C of actual peak Temperature (t _P)		20 - 40 Seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T _P)		8 minutes Max
Do not exceed		280°C

Dimensions

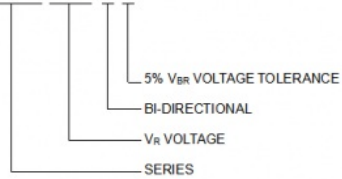
DO-214AB (SMC)



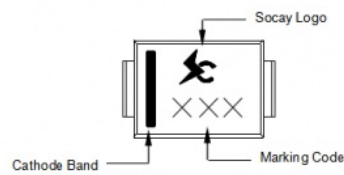
Dimensions	Inches		Millimeters	
	Min	Max	Min	Max
A	0.108	0.126	2.750	3.200
B	0.260	0.280	6.520	7.110
C	0.217	0.244	5.520	6.220
D	0.080	0.112	2.050	2.850
E	0.030	0.060	0.750	1.520
F	-	0.008	-	0.203
G	0.305	0.320	7.640	8.130
H	0.006	0.012	0.150	0.310
I	0.121	-	3.070	-
J	0.068	-	1.715	-
K	-	0.185	-	4.690
L	0.068	-	1.715	-

Part Numbering

SMCJ***CA



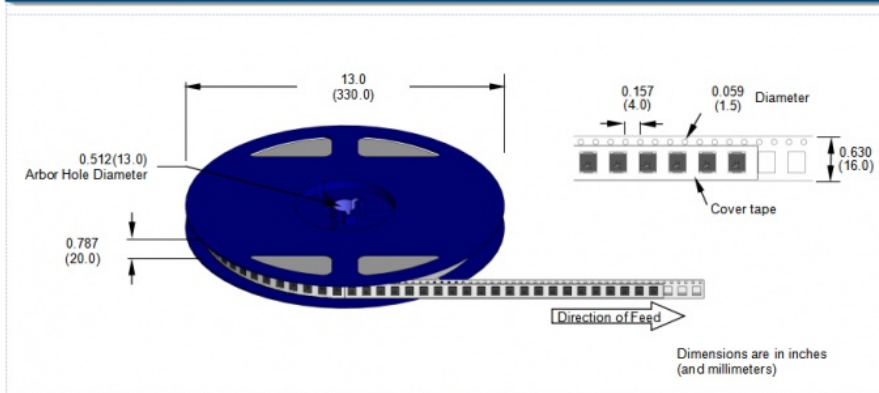
Part Marking



Packaging

Part Number	Component Package	Reel (pcs)	Per Carton (pcs)	Packaging Option	Reel Diameters (mm)
SMCJXXXX	DO-214AB (SMC)	3000	48000	Tape & Reel - 20mm/13"tape	330.0

Tape and Reel Specifications



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